

**Product data sheet** 

### 1. General description

AC Thyristor Triac power switch in a TO220 plastic package with self-protective clamping capabilities against low and high energy transients.

### 2. Features and benefits

- Clamping structure ensuring safe high over-voltage withstand capability
- High junction operating temperature capability
- Full cycle AC conduction
- · Over-voltage withstand capability to IEC 61000-4-5
- Pin compatible with standard triacs
- Planar passivated for voltage ruggedness and reliability
- Protective self turn-on capability for high energy transients
- Safe clamping capability for low energy over-voltage transients
- Less sensitive gate for high noise immunity
- Triggering in three quadrants only
- Very high immunity to false turn-on by dV/dt

### 3. Applications

- AC fan, pump and compressor controls
- Highly inductive, resistive and safety loads
- Large and small appliances (White Goods)
- Reversing induction motor controls

### 4. Quick reference data

Table 1. Q	uick reference data					
Symbol	Parameter	Conditions	Min	Тур	Max	Unit
$V_{\text{DRM}}$	repetitive peak off-state voltage		-	-	800	V
$I_{T(RMS)}$	RMS on-state current	full sine wave; T <sub>mb</sub> ≤ 120 °C; <u>Fig. 1;</u> <u>Fig. 2</u> ; <u>Fig. 3</u>	-	-	12	A
I <sub>TSM</sub>	non-repetitive peak on- state current	full sine wave; T <sub>j(init)</sub> = 25 °C; t <sub>p</sub> = 20 ms; <u>Fig. 4; Fig. 5</u>	-	-	120	A
		full sine wave; $T_{j(init)}$ = 25 °C; $t_p$ = 16.7 ms	-	-	132	А
Tj	junction temperature		-	-	150	°C
V <sub>PP</sub>	peak pulse voltage	T <sub>j</sub> = 25 °C; non-repetitive, off-state; <u>Fig. 6</u>	-	-	2	kV
Static ch	aracteristics					
I <sub>GT</sub>	gate trigger current	V <sub>D</sub> = 12 V; I <sub>T</sub> = 100 mA; LD+ G+; T <sub>j</sub> = 25 °C; <u>Fig. 8</u>	-	-	35	mA
		V <sub>D</sub> = 12 V; I <sub>T</sub> = 100 mA; LD+ G-; T <sub>j</sub> = 25 °C; <u>Fig. 8</u>	-	-	35	mA
		V <sub>D</sub> = 12 V; I <sub>T</sub> = 100 mA; LD- G-; T <sub>j</sub> = 25 °C; <u>Fig. 8</u>	-	-	35	mA

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Symbol	Parameter	Conditions	Min	Тур	Max	Unit
I <sub>H</sub>	holding current	V <sub>D</sub> = 12 V; T <sub>j</sub> = 25 °C; <u>Fig. 10</u>	-	-	50	mA
V <sub>T</sub>	on-state voltage	I <sub>T</sub> = 17 A; T <sub>j</sub> = 25 °C; <u>Fig. 11</u>	-	1.25	1.5	V
V <sub>CL</sub>	clamping voltage	$I_{CL}$ = 0.1 mA; $t_p$ = 1 ms; $T_j$ = 25 °C	850	-	-	V
Dynamic	characteristics					
dV <sub>D</sub> /dt	rate of rise of off-state voltage	$V_{DM}$ = 536 V; T <sub>j</sub> = 150 °C; (V <sub>DM</sub> = 67% of V <sub>DRM</sub> ); exponential waveform; gate open circuit	500	-	-	V/µs
dl <sub>com</sub> /dt	rate of change of commutating current	$    V_{\rm D} = 400 \text{ V};  \text{T}_{\rm j} = 150 \ ^{\circ}\text{C};  \text{I}_{\text{T(RMS)}} = 12 \text{ A}; \\                                  $	5	-	-	A/ms

### 5. Pinning information

Table 2.	Pinning infor	mation		
Pin	Symbol	Description	Simplified outline	Graphic symbol
1	СМ	common	mb	LD
2	LD	load	۲ C f	
3	G	gate		G—Ź
mb	LD	mounting base; load		ĊM 003aaf296

### 6. Ordering information

#### Table 3. Ordering information Orderable part number **Small packing** Package Package Type number Package Packing Name method quantity version issue date ACTT12-800CT TO220 ACTT12-800CTQ Tube 50 SOT78 13-Jun-2008

# 7. Marking

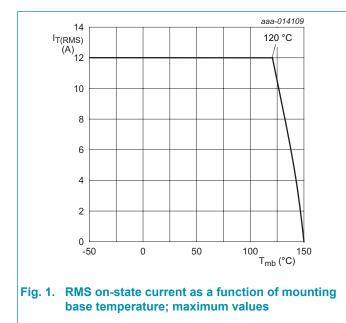
#### Table 4. Marking codes **Type number Marking codes** Assembly factory: d Assembly factory: A ACTT12-800CT ACTT12 ACTT12 800CT 800CT PJdxxxx xx PJAxxxx xx

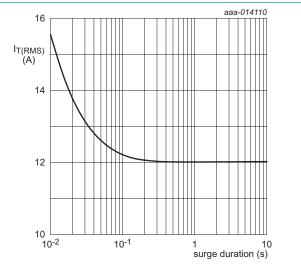
# 8. Limiting values

### Table 5. Limiting values

In accordance with the Absolute Maximum Rating System (IEC 60134).

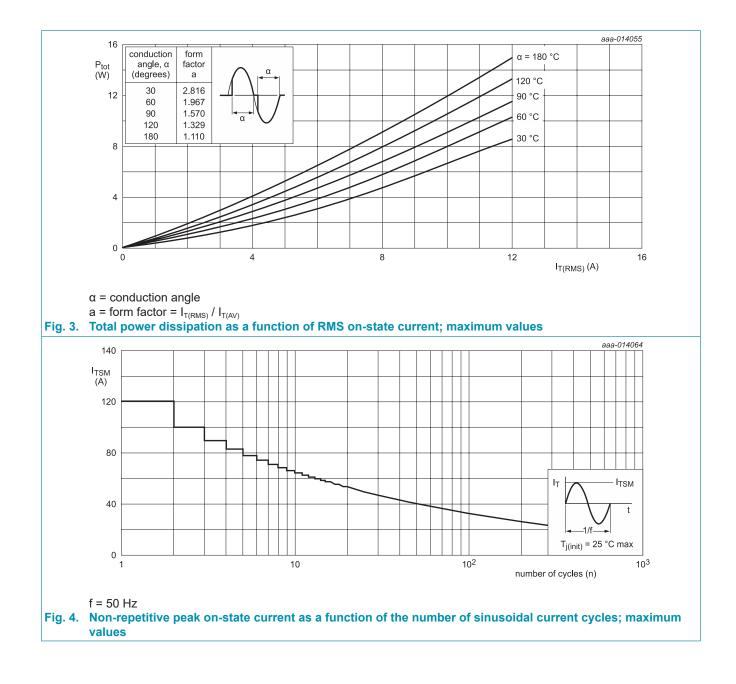
Symbol	Parameter	Conditions	Min	Max	Unit
V <sub>DRM</sub>	repetitive peak off-state voltage		-	800	V
I <sub>T(RMS)</sub>	RMS on-state current	full sine wave; T <sub>mb</sub> ≤ 120 °C; <u>Fig. 1;</u> <u>Fig. 2</u> ; <u>Fig. 3</u>	-	12	A
I <sub>TSM</sub>	non-repetitive peak on-state current	full sine wave; T <sub>j(init)</sub> = 25 °C; t <sub>p</sub> = 20 ms; <u>Fig. 4; Fig. 5</u>	-	120	A
		full sine wave; $T_{j(init)}$ = 25 °C; $t_p$ = 16.7 ms	-	132	А
l <sup>2</sup> t	l <sup>2</sup> t for fusing	$t_p$ = 10 ms; sine-wave pulse	-	72	A <sup>2</sup> s
dl <sub>⊤</sub> /dt	rate of rise of on-state current	I <sub>G</sub> = 0.2 A	-	100	A/µs
I <sub>GM</sub>	peak gate current	t <sub>p</sub> = 20 μs	-	2	А
P <sub>GM</sub>	peak gate power		-	5	W
$P_{G(AV)}$	average gate power	over any 20 ms period	-	0.5	W
T <sub>stg</sub>	storage temperature		-40	150	°C
Tj	junction temperature		-	150	°C
V <sub>PP</sub>	peak pulse voltage	T <sub>j</sub> = 25 °C; non-repetitive, off-state; <u>Fig. 6</u>	-	2	kV

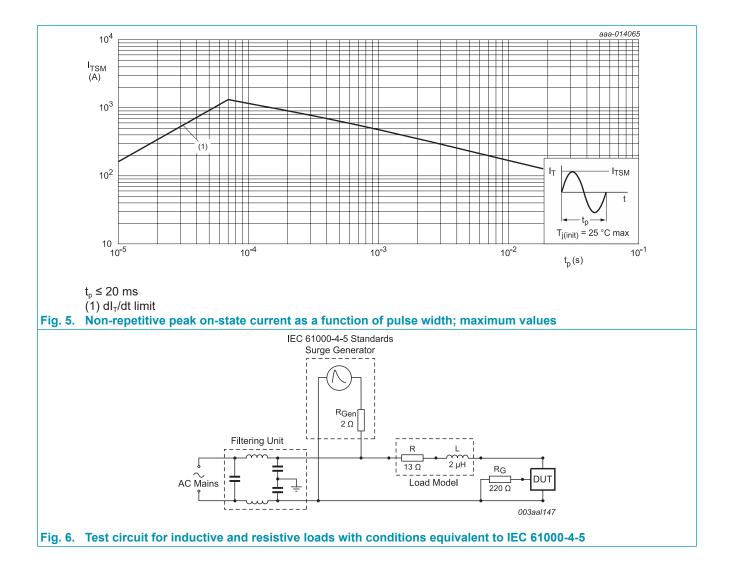






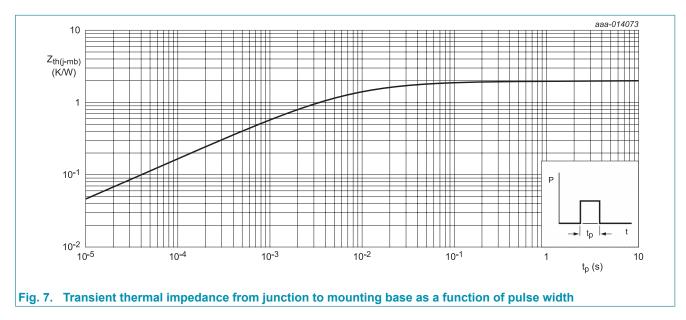
### AC Thyristor Triac power switch





### 9. Thermal characteristics

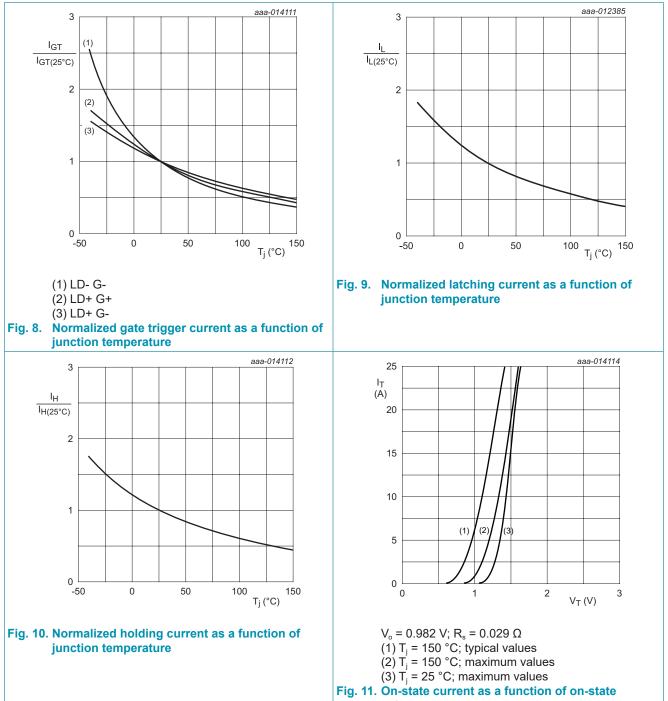
Table 6. Thermal characteristics								
Symbol	Parameter	Conditions		Min	Тур	Max	Unit	
$R_{\text{th(j-mb)}}$	thermal resistance from junction to mounting base	full cycle; <u>Fig. 7</u>		-	-	2	K/W	
$R_{\text{th(j-a)}}$	thermal resistance from junction to ambient	in free air		-	60	-	K/W	



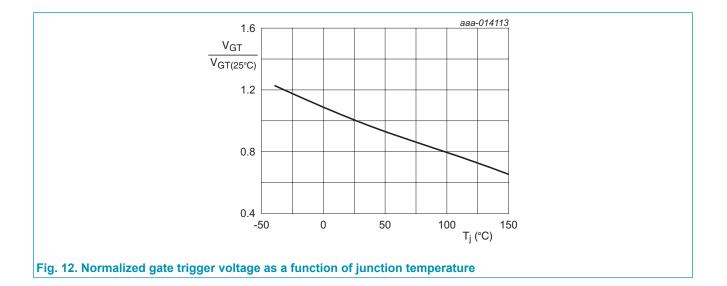
## **10. Characteristics**

Symbol	Parameter	Conditions	Min	Тур	Max	Unit
Static cha	aracteristics					
I <sub>GT</sub>	gate trigger current	$V_{D} = 12 \text{ V}; \text{ I}_{T} = 100 \text{ mA}; \text{ LD+ G+};$ $T_{j} = 25 \text{ °C}; \text{ Fig. 8}$	-	-	35	mA
		$V_{\rm D}$ = 12 V; I <sub>T</sub> = 100 mA; LD+ G-; T <sub>j</sub> = 25 °C; Fig. 8	-	-	35	mA
		$V_{\rm D}$ = 12 V; I <sub>T</sub> = 100 mA; LD- G-; T <sub>j</sub> = 25 °C; Fig. 8	-	-	35	mA
I <sub>L</sub>	latching current	$V_{\rm D}$ = 12 V; I <sub>G</sub> = 100 mA; LD+ G+; T <sub>j</sub> = 25 °C; <u>Fig. 9</u>	-	-	50	mA
		$V_{\rm D}$ = 12 V; I <sub>G</sub> = 100 mA; LD+ G-; T <sub>j</sub> = 25 °C; <u>Fig. 9</u>	-	-	70	mA
		$V_{\rm D}$ = 12 V; I <sub>G</sub> = 100 mA; LD- G-; T <sub>j</sub> = 25 °C; Fig. 9	-	-	50	mA
I <sub>H</sub>	holding current	V <sub>D</sub> = 12 V; T <sub>j</sub> = 25 °C; <u>Fig. 10</u>	-	-	50	mA
V <sub>T</sub>	on-state voltage	I <sub>T</sub> = 17 A; T <sub>j</sub> = 25 °C; <u>Fig. 11</u>	-	1.25	1.5	V
$V_{\text{GT}}$	gate trigger voltage	$V_{D}$ = 12 V; I <sub>T</sub> = 100 mA; T <sub>j</sub> = 25 °C; Fig. 12	-	0.8	1	V
		$V_{\rm D}$ = 400 V; I <sub>T</sub> = 100 mA; T <sub>j</sub> = 150 °C	0.2	0.45	-	V
I <sub>D</sub>	off-state current	V <sub>D</sub> = 800 V; T <sub>j</sub> = 25 °C	-	-	10	μA
		V <sub>D</sub> = 800 V; T <sub>j</sub> = 150 °C	-	-	2	mA
V <sub>CL</sub>	clamping voltage	$I_{CL} = 0.1 \text{ mA}; t_p = 1 \text{ ms}; T_j = 25 \text{ °C}$	850	-	-	V
Dynamic	characteristics	· · · · · ·				
dV <sub>D</sub> /dt	rate of rise of off-state voltage	$V_{DM}$ = 536 V; T <sub>j</sub> = 150 °C; (V <sub>DM</sub> = 67% of V <sub>DRM</sub> ); exponential waveform; gate open circuit	500	-	-	V/µs
dl <sub>com</sub> /dt	rate of change of commutating current	$V_D = 400 \text{ V}; \text{ T}_j = 150 \text{ °C}; \text{ I}_{T(RMS)} = 12 \text{ A};$ $dV_{com}/dt = 20 \text{ V}/\mu \text{s}; \text{ (snubberless condition); gate open circuit}$	5	-	-	A/ms

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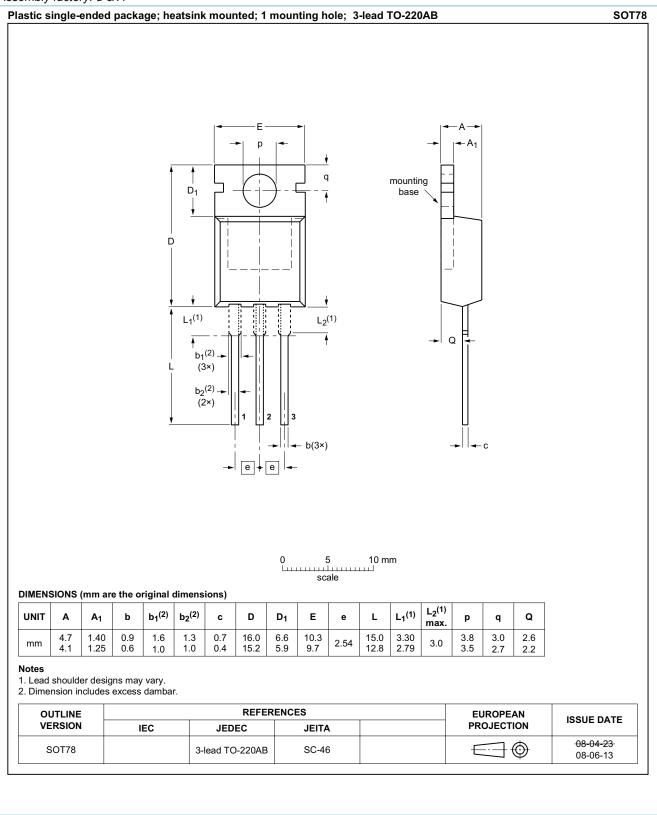


voltage



### **11. Package outline**

### Assembly factory: d & A



### **AC Thyristor Triac power switch**

# 12. Legal information

#### Data sheet status

Document status [1][2]	Product status [3]	Definition
Objective [short] data sheet	Development	This document contains data from the objective specification for product development.
Preliminary [short] data sheet	Qualification	This document contains data from the preliminary specification.
Product [short] data sheet	Production	This document contains the product specification.

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